

RJH1CV7DPQ-E0

1200V - 35A - IGBT

Application: Inverter

R07DS0525EJ0800

Rev.8.00

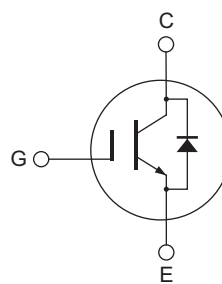
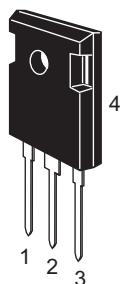
Nov 05, 2014

Features

- Short circuit withstand time (5 μ s typ.)
- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.8$ V typ. (at $I_C = 35$ A, $V_{GE} = 15$ V, $T_a = 25^\circ\text{C}$)
- Built-in fast recovery diode ($t_{tr} = 200$ ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching
 $t_f = 280$ ns typ. (at $V_{CC} = 600$ V, $V_{GE} = 15$ V, $I_C = 35$ A, $R_g = 5$ Ω , $T_a = 25^\circ\text{C}$, inductive load)

Outline

RENESAS Package code: PRSS0003ZE-A
(Package name: TO-247)



1. Gate
2. Collector
3. Emitter
4. Collector

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V_{CES} / V_R	1200	V
Gate to emitter voltage		V_{GES}	± 30	V
Collector current	$T_c = 25^\circ\text{C}$	I_C	70	A
	$T_c = 100^\circ\text{C}$	I_C	35	A
Collector peak current		$i_{c(peak)}$ ^{Note1}	105	A
Collector to emitter diode forward current		I_{DF}	35	A
Collector to emitter diode forward peak current		$i_{DF(peak)}$ ^{Note1}	105	A
Collector dissipation		P_C ^{Note2}	320	W
Junction to case thermal resistance (IGBT)		θ_{j-c} ^{Note2}	0.39	$^\circ\text{C/W}$
Junction to case thermal resistance (Diode)		θ_{j-cd} ^{Note2}	0.69	$^\circ\text{C/W}$
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10$ μ s, duty cycle $\leq 1\%$

2. Value at $T_c = 25^\circ\text{C}$

Electrical Characteristics

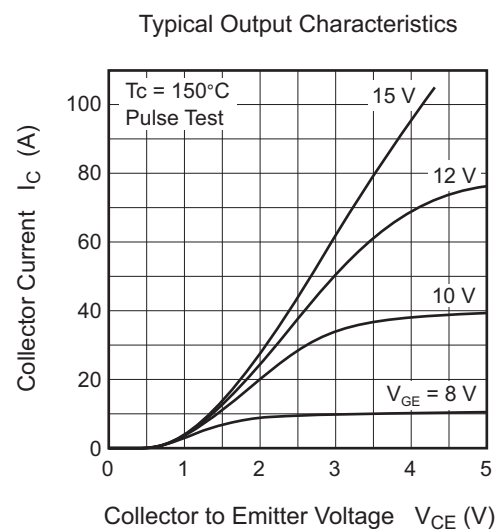
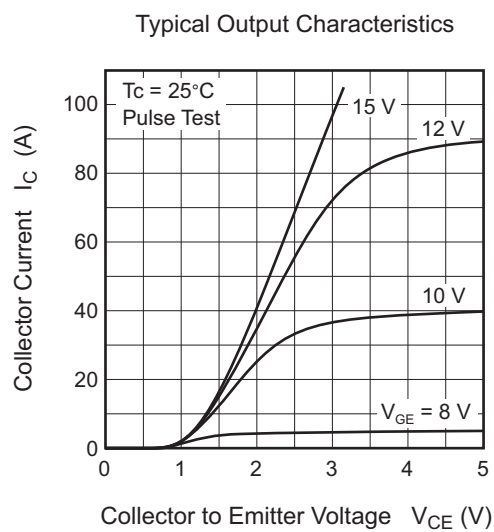
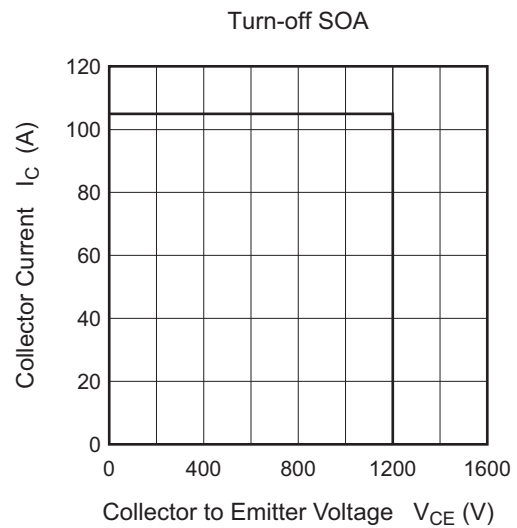
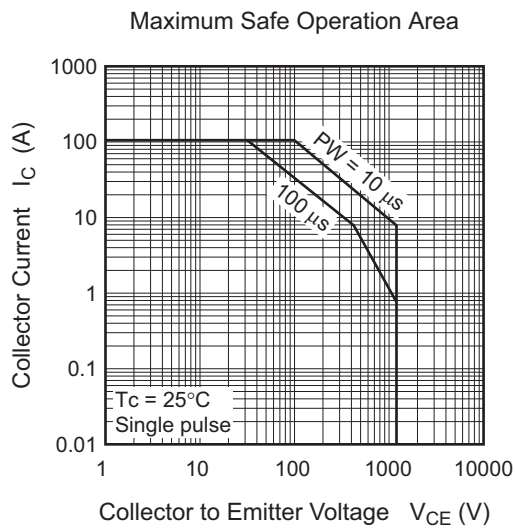
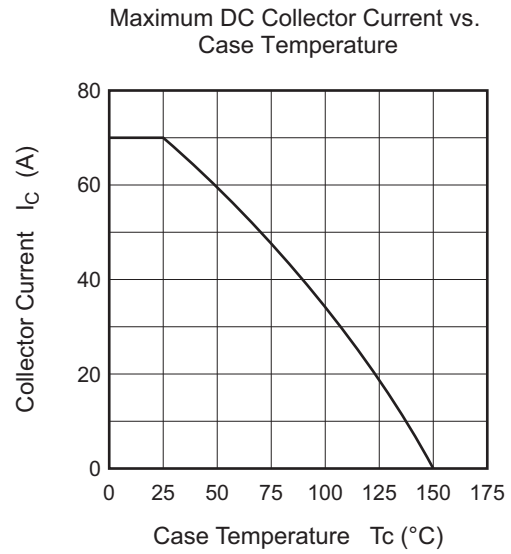
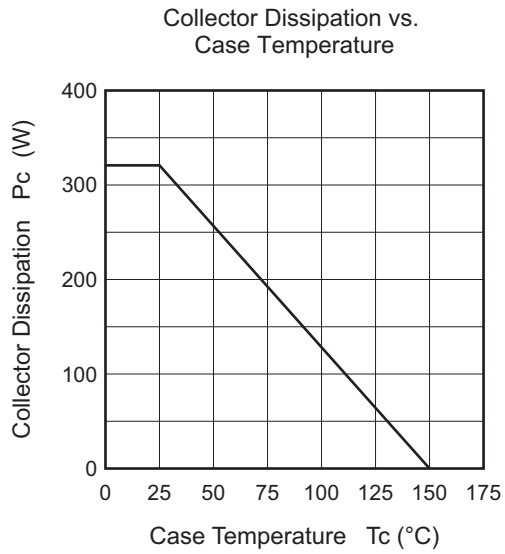
(Ta = 25°C)

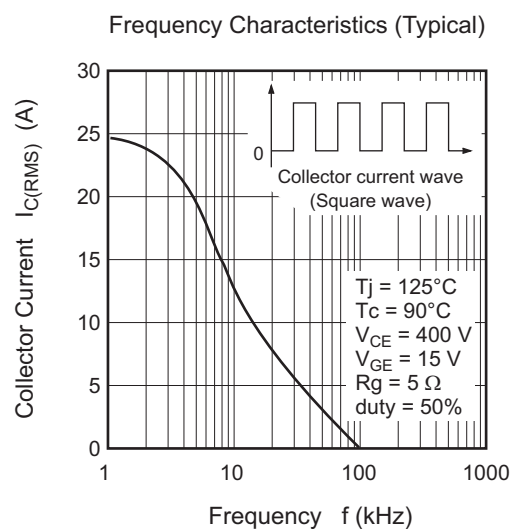
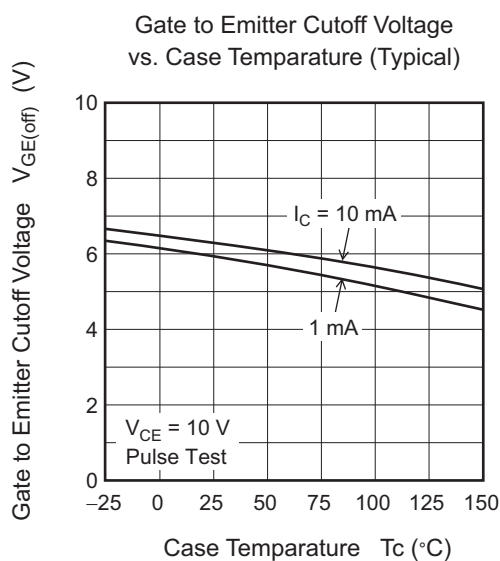
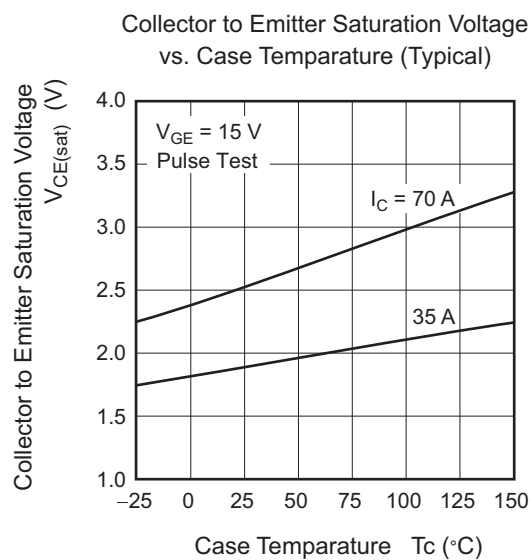
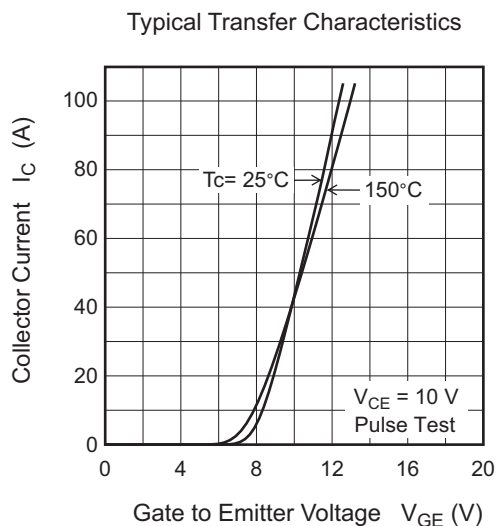
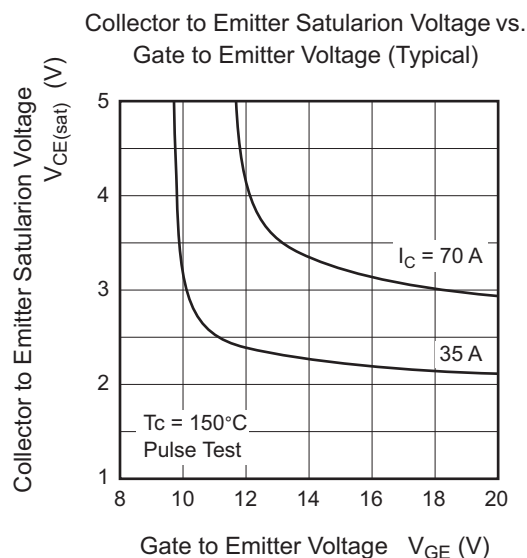
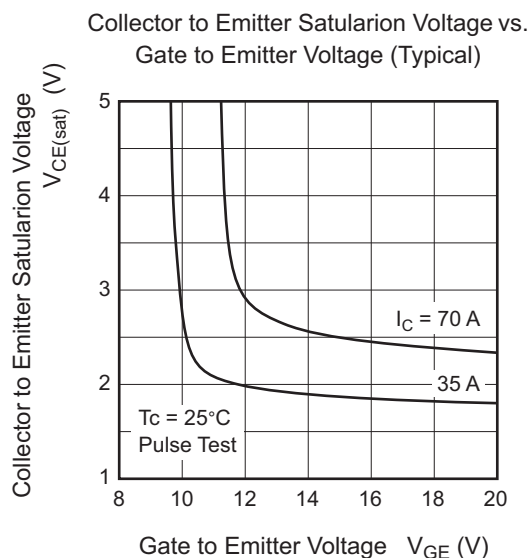
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current / Diode reverse current	I_{CES}/I_R	—	—	100	μA	$V_{CE} = 1200 V, V_{GE} = 0$
Gate to emitter leak current	I_{GES}	—	—	± 1	μA	$V_{GE} = \pm 30 V, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.5	—	6.5	V	$V_{CE} = 10 V, I_C = 1 mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	1.8	2.3	V	$I_C = 35 A, V_{GE} = 15 V$ ^{Note3}
	$V_{CE(sat)}$	—	2.5	—	V	$I_C = 70 A, V_{GE} = 15 V$ ^{Note3}
Input capacitance	C_{ies}	—	2150	—	pF	$V_{CE} = 25 V$
Output capacitance	C_{oes}	—	100	—	pF	$V_{GE} = 0$
Reverse transfer capacitance	C_{res}	—	55	—	pF	$f = 1 MHz$
Total gate charge	Q_g	—	166	—	nC	$V_{GE} = 15 V$
Gate to emitter charge	Q_{ge}	—	20	—	nC	$V_{CE} = 300 V$
Gate to collector charge	Q_{gc}	—	95	—	nC	$I_C = 35 A$
Turn-on delay time	$t_{d(on)}$	—	53	—	ns	$V_{CC} = 600 V$
Rise time	t_r	—	45	—	ns	$V_{GE} = 15 V$
Turn-off delay time	$t_{d(off)}$	—	185	—	ns	$I_C = 35 A$
Fall time	t_f	—	280	—	ns	$R_g = 5 \Omega$
Turn-on energy	E_{on}	—	3.2	—	mJ	Inductive load
Turn-off energy	E_{off}	—	2.5	—	mJ	
Total switching energy	E_{total}	—	5.7	—	mJ	
Short circuit withstand time	t_{sc}	—	5	—	μs	$V_{CC} \leq 720 V, V_{GE} = 15 V$ $T_c \leq 125^\circ C$

FRD forward voltage	V_F	—	2.1	—	V	$I_F = 35 A$ ^{Note3}
FRD reverse recovery time	t_{rr}	—	200	—	ns	$I_F = 35 A$ $di_F/dt = 100 A/\mu s$
FRD reverse recovery charge	Q_{rr}	—	0.7	—	μC	
FRD peak reverse recovery current	I_{rr}	—	9.6	—	A	

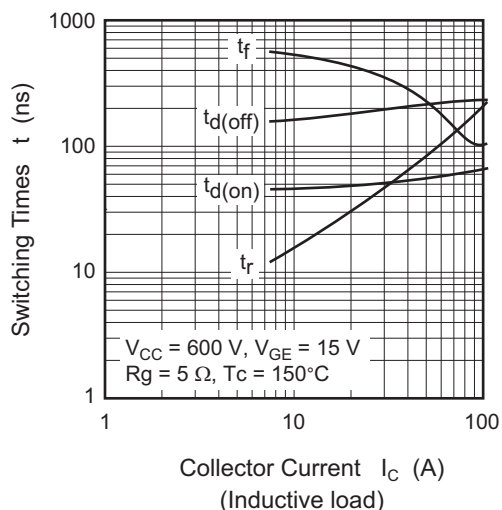
Notes: 3. Pulse test.

Main Characteristics

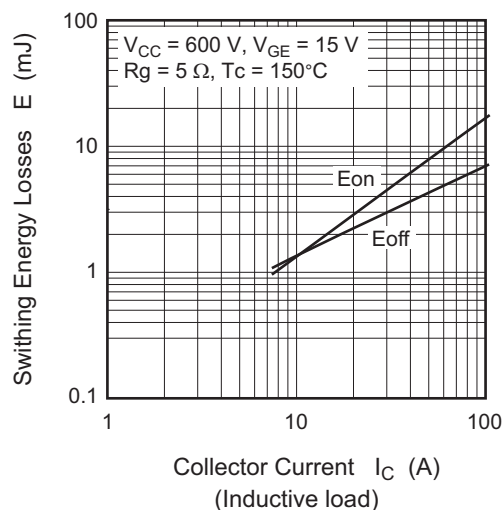




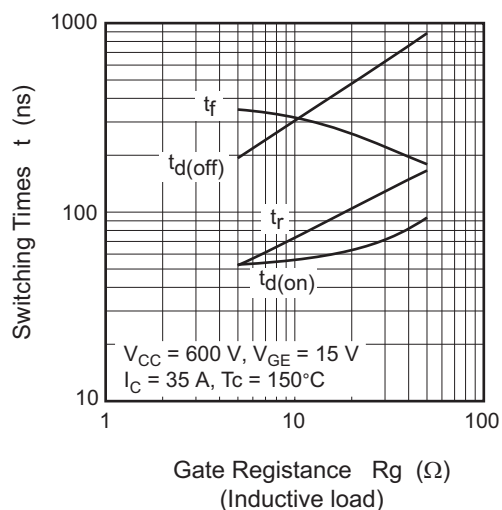
Switching Characteristics (Typical) (1)



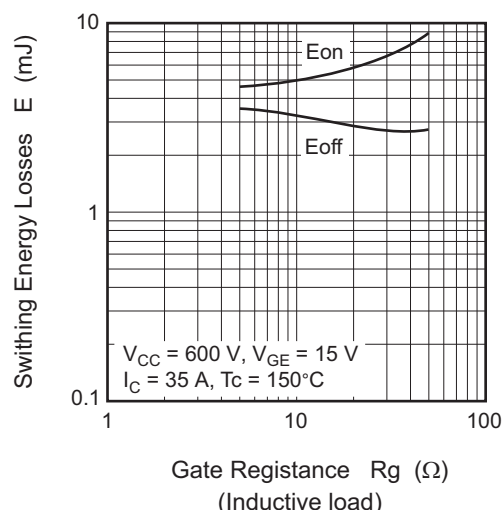
Switching Characteristics (Typical) (2)



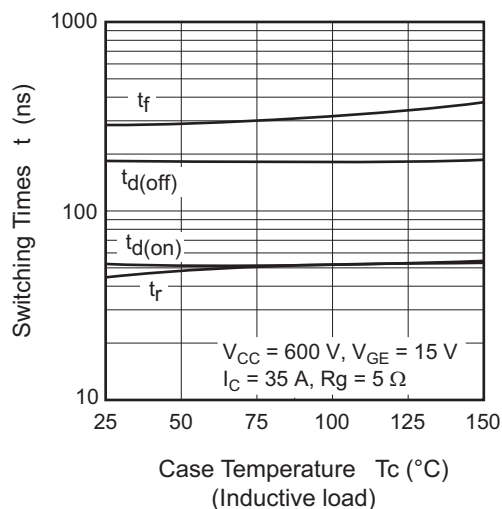
Switching Characteristics (Typical) (3)



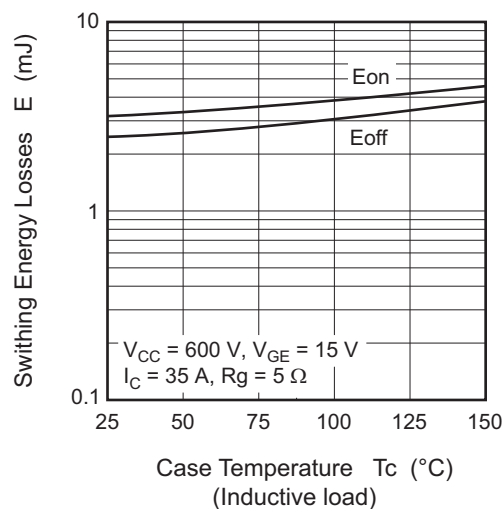
Switching Characteristics (Typical) (4)

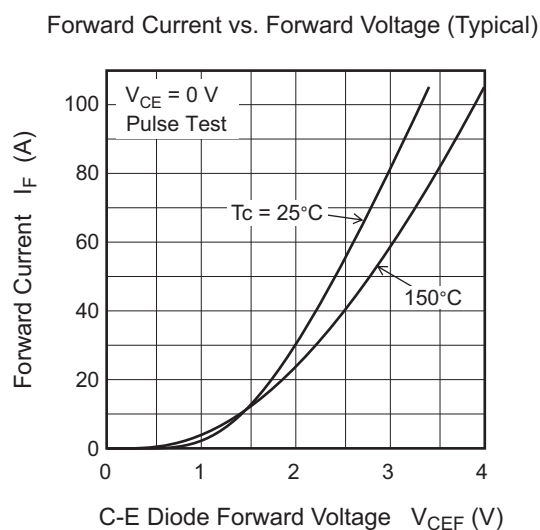
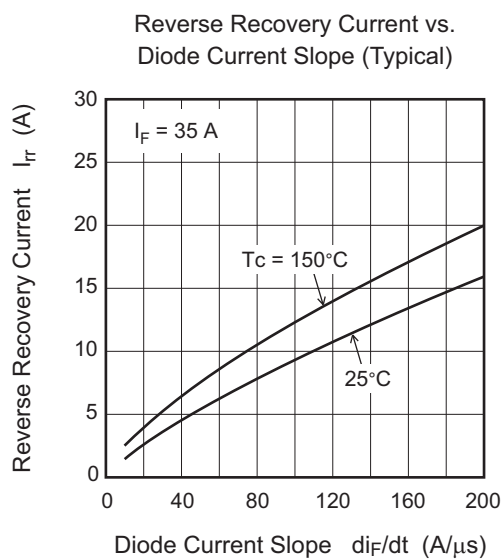
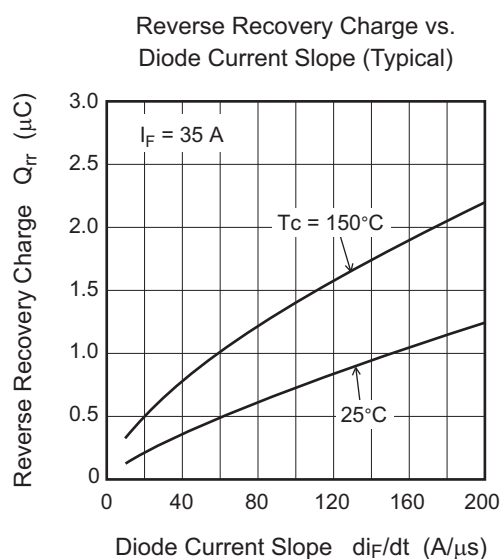
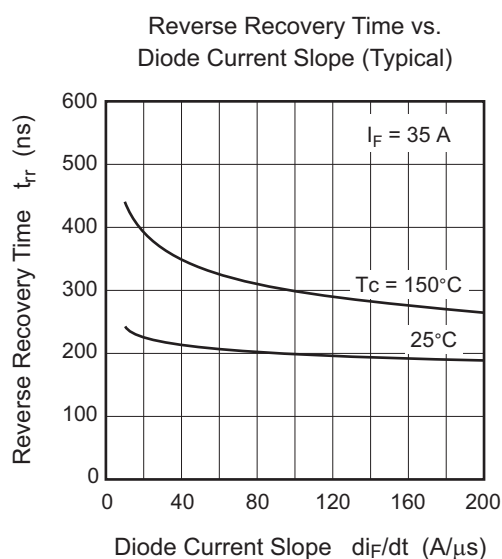
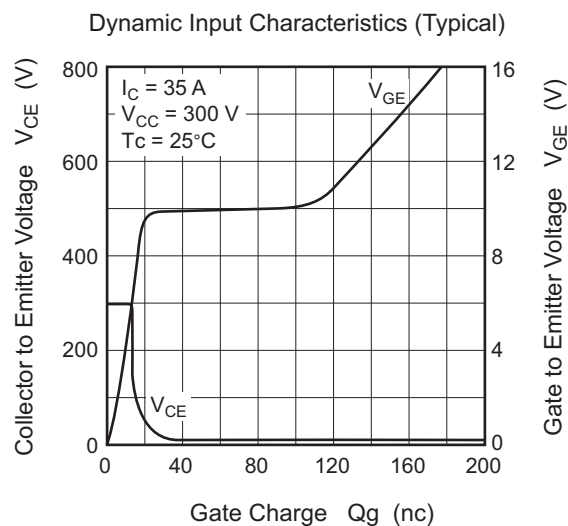
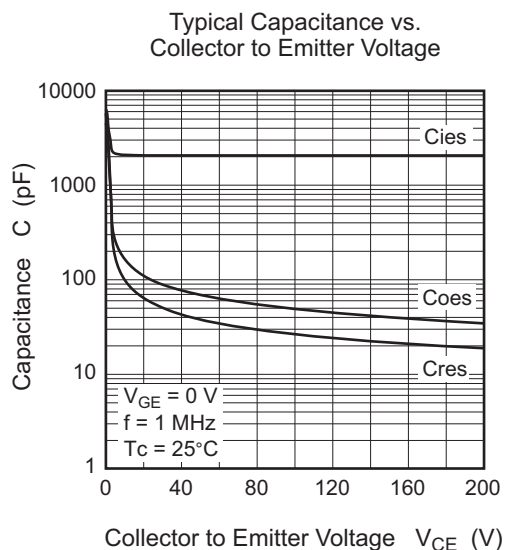


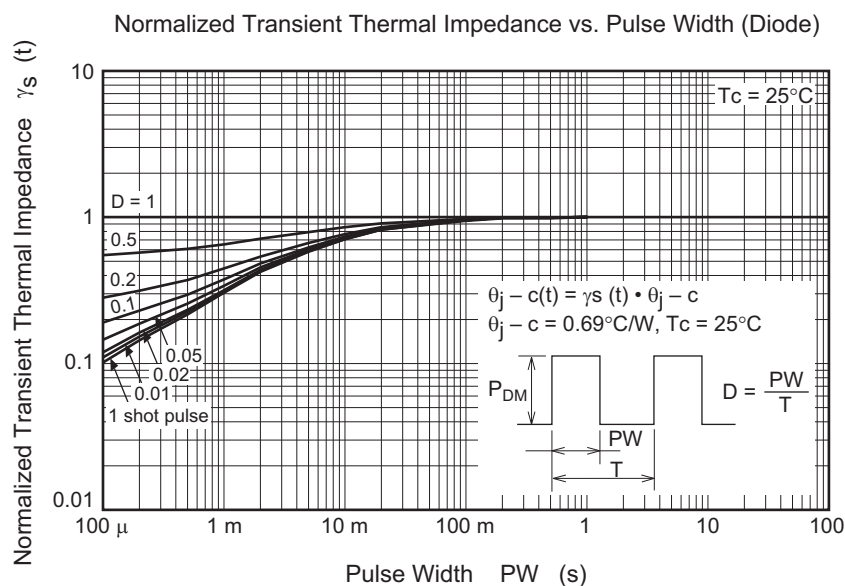
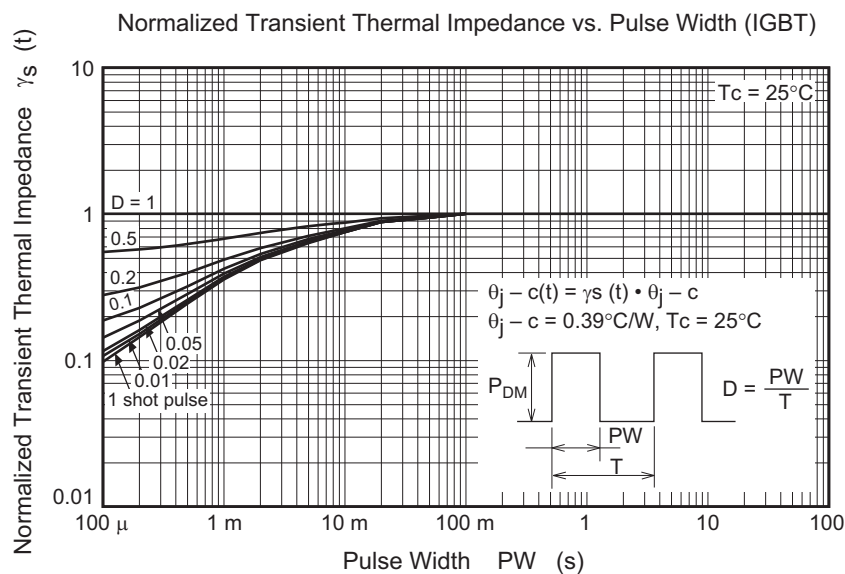
Switching Characteristics (Typical) (5)



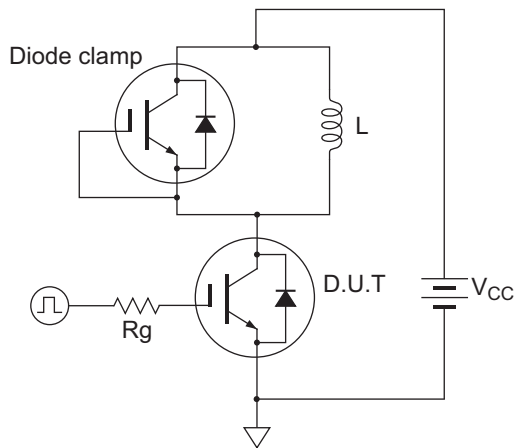
Switching Characteristics (Typical) (6)



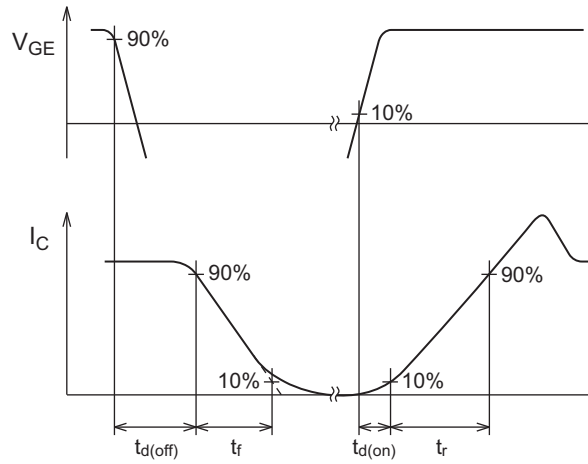




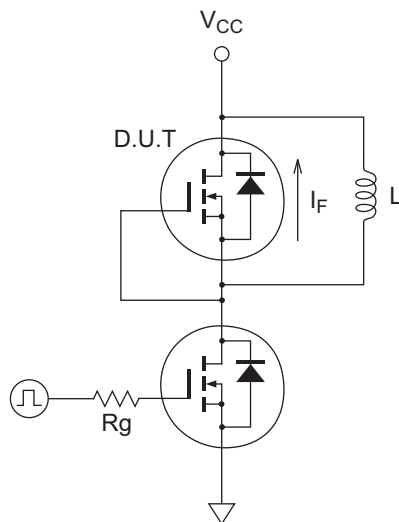
Switching Time Test Circuit



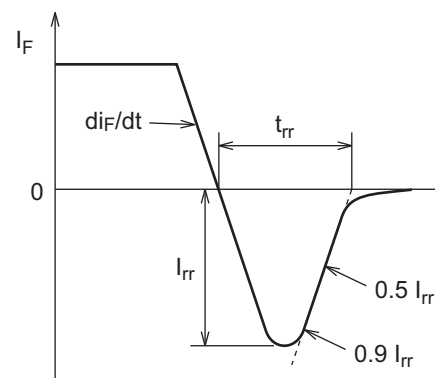
Waveform



Diode Reverse Recovery Time Test Circuit



Waveform



Package Dimension

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-247	—	PRSS0003ZE-A	—	6.0g	

Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CV7DPQ-E0#T2	450 pcs	Tube

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Renesas Electronics America Inc.

2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited

1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.

Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited

Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-6688, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
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Renesas Electronics Singapore Pte. Ltd.

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Tel: +65-6213-0200, Fax: +65-6213-0300

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